

# Thyristor Module

$$V_{RRM} = 1200V$$

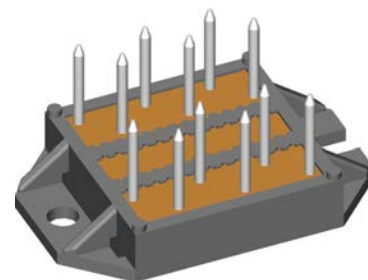
$$I_{TAV} = 16A$$

$$V_T = 1,19V$$

AC Controlling  
 3~ full-controlled

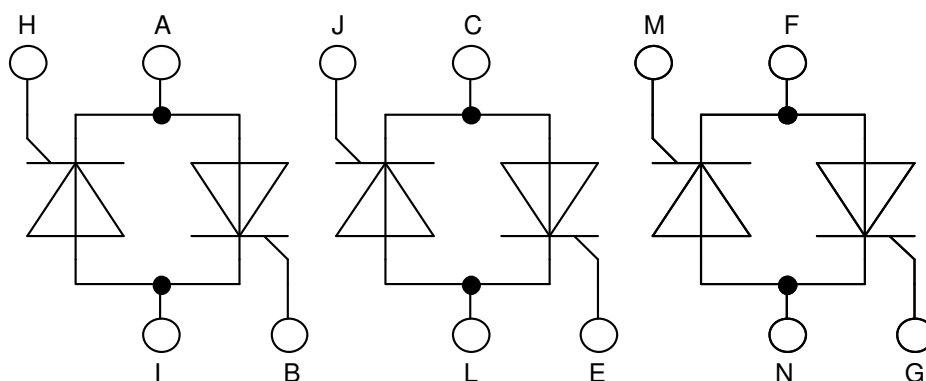
Part number

**VWO35-12H07**



Backside: isolated

 E72873



## Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al<sub>2</sub>O<sub>3</sub>-ceramic

## Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

## Package: ECO-PAC1

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

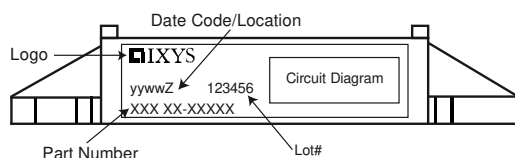
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| Rectifier      |                                                             |                                                                                                                                                                        |                                | Ratings |      |      |                  |
|----------------|-------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------|---------|------|------|------------------|
| Symbol         | Definition                                                  | Conditions                                                                                                                                                             |                                | min.    | typ. | max. | Unit             |
| $V_{RSM/DSM}$  | <b>max. non-repetitive reverse/forward blocking voltage</b> | $T_{VJ} = 25^{\circ}\text{C}$                                                                                                                                          |                                |         |      | 1300 | V                |
| $V_{RRM/DRM}$  | <b>max. repetitive reverse/forward blocking voltage</b>     | $T_{VJ} = 25^{\circ}\text{C}$                                                                                                                                          |                                |         |      | 1200 | V                |
| $I_{R/D}$      | <b>reverse current, drain current</b>                       | $V_{R/D} = 1200\text{ V}$                                                                                                                                              | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 50   | $\mu\text{A}$    |
|                |                                                             | $V_{R/D} = 1200\text{ V}$                                                                                                                                              | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 2    | mA               |
| $V_T$          | <b>forward voltage drop</b>                                 | $I_T = 15\text{ A}$                                                                                                                                                    | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1,23 | V                |
|                |                                                             | $I_T = 30\text{ A}$                                                                                                                                                    |                                |         |      | 1,48 | V                |
|                |                                                             | $I_T = 15\text{ A}$                                                                                                                                                    | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 1,19 | V                |
|                |                                                             | $I_T = 30\text{ A}$                                                                                                                                                    |                                |         |      | 1,51 | V                |
| $I_{TAV}$      | <b>average forward current</b>                              | $T_C = 85^{\circ}\text{C}$                                                                                                                                             | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 16   | A                |
| $I_{RMS}$      | <b>RMS forward current per phase</b>                        | 180° sine                                                                                                                                                              |                                |         |      | 35   | A                |
| $V_{T0}$       | <b>threshold voltage</b>                                    | } <b>for power loss calculation only</b>                                                                                                                               | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 0,88 | V                |
| $r_T$          | <b>slope resistance</b>                                     |                                                                                                                                                                        |                                |         |      | 21   | m $\Omega$       |
| $R_{thJC}$     | <b>thermal resistance junction to case</b>                  |                                                                                                                                                                        |                                |         |      | 1,3  | K/W              |
| $R_{thCH}$     | <b>thermal resistance case to heatsink</b>                  |                                                                                                                                                                        |                                |         | 0,5  |      | K/W              |
| $P_{tot}$      | <b>total power dissipation</b>                              |                                                                                                                                                                        | $T_C = 25^{\circ}\text{C}$     |         |      | 77   | W                |
| $I_{TSM}$      | <b>max. forward surge current</b>                           | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                       | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 200  | A                |
|                |                                                             | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                      | $V_R = 0\text{ V}$             |         |      | 215  | A                |
|                |                                                             | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                       | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 170  | A                |
|                |                                                             | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                      | $V_R = 0\text{ V}$             |         |      | 185  | A                |
| $I^2t$         | <b>value for fusing</b>                                     | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                       | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 200  | A <sup>2</sup> s |
|                |                                                             | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                      | $V_R = 0\text{ V}$             |         |      | 190  | A <sup>2</sup> s |
|                |                                                             | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                       | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 145  | A <sup>2</sup> s |
|                |                                                             | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                      | $V_R = 0\text{ V}$             |         |      | 140  | A <sup>2</sup> s |
| $C_J$          | <b>junction capacitance</b>                                 | $V_R = 400\text{ V}$ $f = 1\text{ MHz}$                                                                                                                                | $T_{VJ} = 25^{\circ}\text{C}$  |         | 7    |      | pF               |
| $P_{GM}$       | <b>max. gate power dissipation</b>                          | $t_p = 30\text{ }\mu\text{s}$                                                                                                                                          | $T_C = 125^{\circ}\text{C}$    |         |      | 5    | W                |
|                |                                                             | $t_p = 300\text{ }\mu\text{s}$                                                                                                                                         |                                |         |      | 2,5  | W                |
| $P_{GAV}$      | <b>average gate power dissipation</b>                       |                                                                                                                                                                        |                                |         |      | 0,5  | W                |
| $(di/dt)_{cr}$ | <b>critical rate of rise of current</b>                     | $T_{VJ} = 125^{\circ}\text{C}; f = 50\text{ Hz}$ repetitive, $I_T = 45\text{ A}$                                                                                       |                                |         |      | 100  | A/ $\mu\text{s}$ |
|                |                                                             | $t_p = 200\text{ }\mu\text{s}; di_G/dt = 0,15\text{ A}/\mu\text{s};$<br>$I_G = 0,15\text{ A}; V_D = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 15\text{ A}$               |                                |         |      | 500  | A/ $\mu\text{s}$ |
| $(dv/dt)_{cr}$ | <b>critical rate of rise of voltage</b>                     | $V_D = \frac{2}{3} V_{DRM}$<br>$R_{GK} = \infty$ ; method 1 (linear voltage rise)                                                                                      | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 500  | V/ $\mu\text{s}$ |
| $V_{GT}$       | <b>gate trigger voltage</b>                                 | $V_D = 6\text{ V}$                                                                                                                                                     | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1,5  | V                |
|                |                                                             |                                                                                                                                                                        | $T_{VJ} = -40^{\circ}\text{C}$ |         |      | 2,5  | V                |
| $I_{GT}$       | <b>gate trigger current</b>                                 | $V_D = 6\text{ V}$                                                                                                                                                     | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 25   | mA               |
|                |                                                             |                                                                                                                                                                        | $T_{VJ} = -40^{\circ}\text{C}$ |         |      | 50   | mA               |
| $V_{GD}$       | <b>gate non-trigger voltage</b>                             | $V_D = \frac{2}{3} V_{DRM}$                                                                                                                                            | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 0,2  | V                |
| $I_{GD}$       | <b>gate non-trigger current</b>                             |                                                                                                                                                                        |                                |         |      | 3    | mA               |
| $I_L$          | <b>latching current</b>                                     | $t_p = 10\text{ }\mu\text{s}$                                                                                                                                          | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 75   | mA               |
|                |                                                             | $I_G = 0,1\text{ A}; di_G/dt = 0,1\text{ A}/\mu\text{s}$                                                                                                               |                                |         |      |      |                  |
| $I_H$          | <b>holding current</b>                                      | $V_D = 6\text{ V}$ $R_{GK} = \infty$                                                                                                                                   | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 50   | mA               |
| $t_{gd}$       | <b>gate controlled delay time</b>                           | $V_D = \frac{1}{2} V_{DRM}$                                                                                                                                            | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 2    | $\mu\text{s}$    |
|                |                                                             | $I_G = 0,1\text{ A}; di_G/dt = 0,1\text{ A}/\mu\text{s}$                                                                                                               |                                |         |      |      |                  |
| $t_q$          | <b>turn-off time</b>                                        | $V_R = 100\text{ V}; I_T = 15\text{ A}; V_D = \frac{2}{3} V_{DRM}$<br>$di/dt = 10\text{ A}/\mu\text{s}; dv/dt = 20\text{ V}/\mu\text{s}; t_p = 200\text{ }\mu\text{s}$ | $T_{VJ} = 100^{\circ}\text{C}$ |         | 150  |      | $\mu\text{s}$    |

| Package ECO-PAC1     |                                                                     |                                         |      | Ratings |      |      |  |
|----------------------|---------------------------------------------------------------------|-----------------------------------------|------|---------|------|------|--|
| Symbol               | Definition                                                          | Conditions                              | min. | typ.    | max. | Unit |  |
| I <sub>RMS</sub>     | <i>RMS current</i>                                                  | per terminal                            |      |         | 40   | A    |  |
| T <sub>VJ</sub>      | <i>virtual junction temperature</i>                                 |                                         | -40  |         | 125  | °C   |  |
| T <sub>op</sub>      | <i>operation temperature</i>                                        |                                         | -40  |         | 100  | °C   |  |
| T <sub>stg</sub>     | <i>storage temperature</i>                                          |                                         | -40  |         | 125  | °C   |  |
| Weight               |                                                                     |                                         |      | 19      |      | g    |  |
| M <sub>D</sub>       | <i>mounting torque</i>                                              |                                         | 1,4  |         | 2    | Nm   |  |
| d <sub>Spp/App</sub> | <i>creepage distance on surface   striking distance through air</i> | <i>terminal to terminal</i>             | 6,0  |         |      | mm   |  |
| d <sub>Spb/Apb</sub> |                                                                     | <i>terminal to backside</i>             | 10,0 |         |      | mm   |  |
| V <sub>ISOL</sub>    | <i>isolation voltage</i>                                            | t = 1 second                            | 3600 |         |      | V    |  |
|                      |                                                                     | t = 1 minute                            | 3000 |         |      | V    |  |
|                      |                                                                     | 50/60 Hz, RMS; I <sub>ISOL</sub> ≤ 1 mA |      |         |      |      |  |

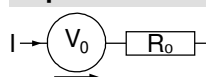


| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | VWO35-12ho7     | VWO35-12ho7        | Box           | 25       | 479667   |

### Equivalent Circuits for Simulation

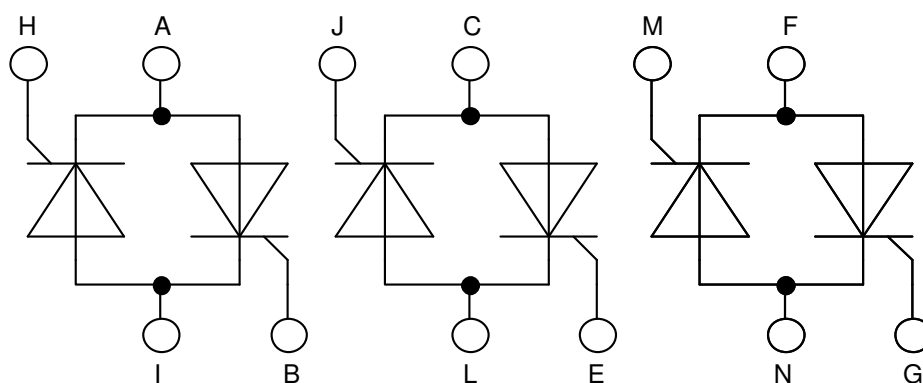
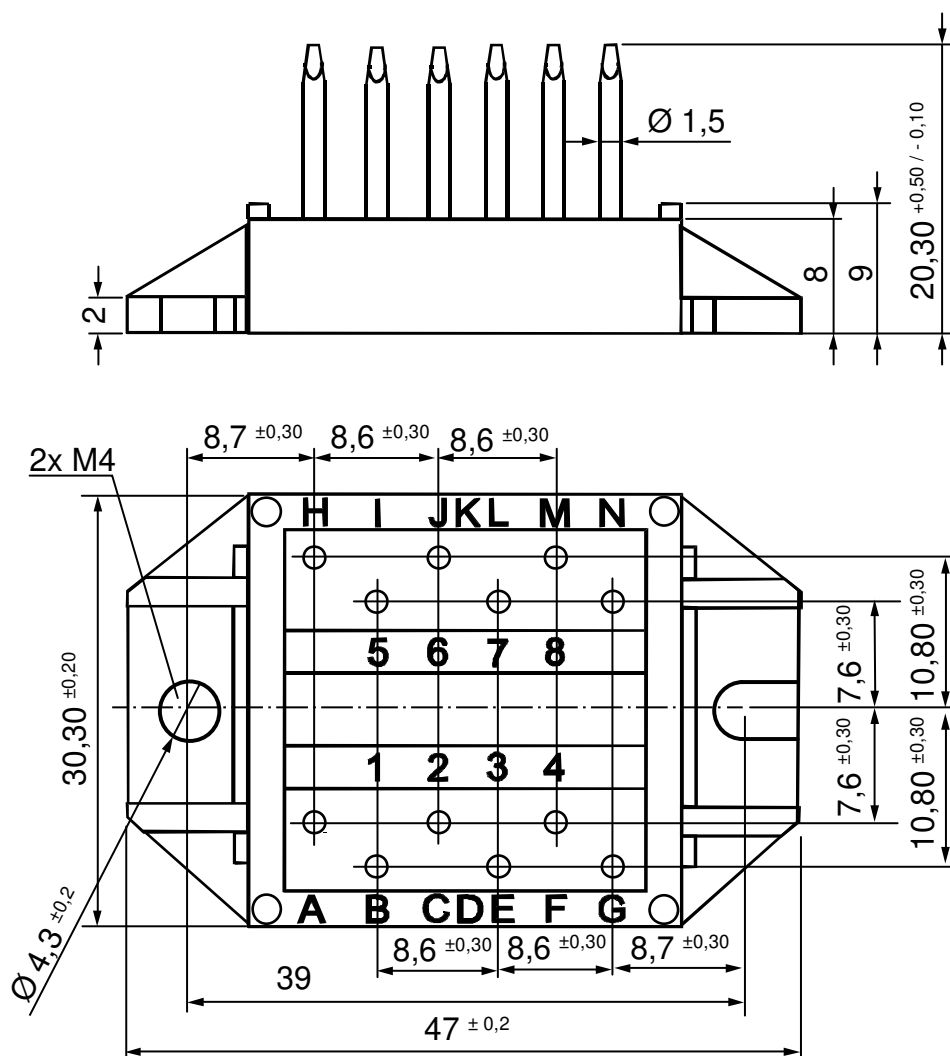
\* on die level

$T_{VJ} = 125^{\circ}\text{C}$



Thyristor

|              |                           |      |    |
|--------------|---------------------------|------|----|
| $V_{0 \max}$ | <b>threshold voltage</b>  | 0,88 | V  |
| $R_{0 \max}$ | <b>slope resistance *</b> | 18   | mΩ |



## Thyristor

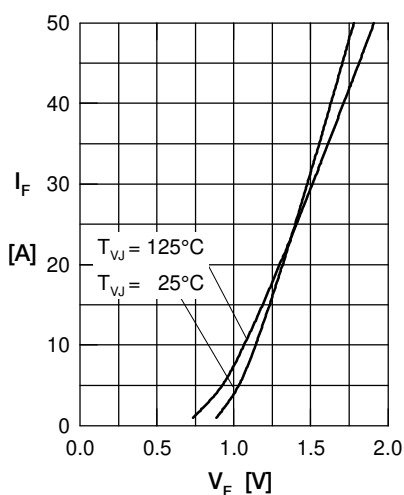


Fig. 1 Forward current vs. voltage drop per thyristor

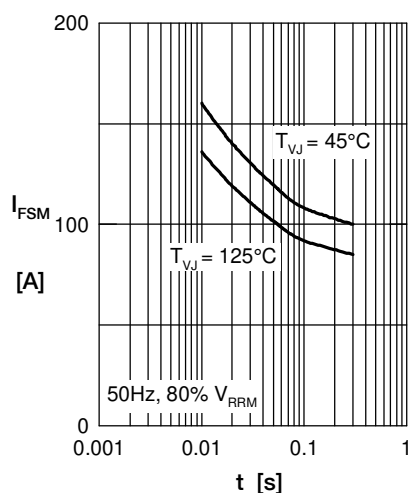


Fig. 2 Surge overload current vs. time per thyristor

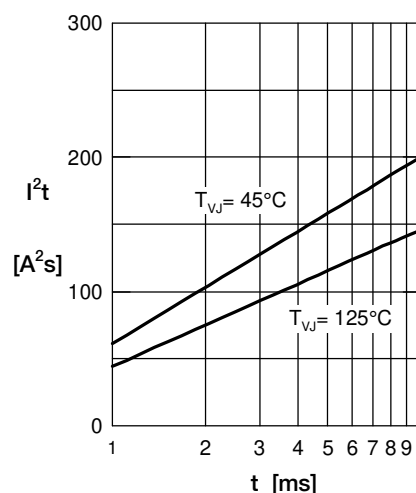


Fig. 3  $I^2t$  vs. time per thyristor

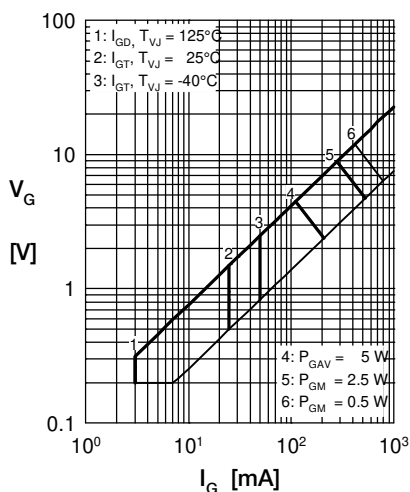


Fig. 4 Gate trigger characteristics

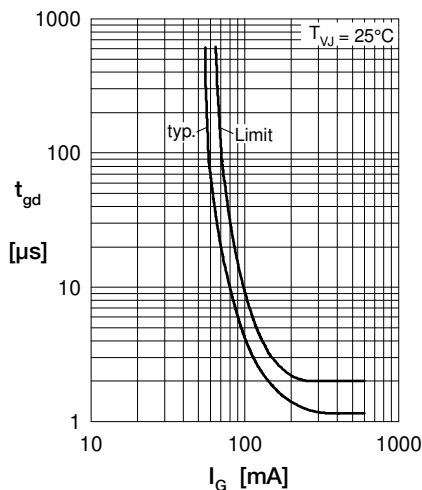


Fig. 5 Gate trigger delay time

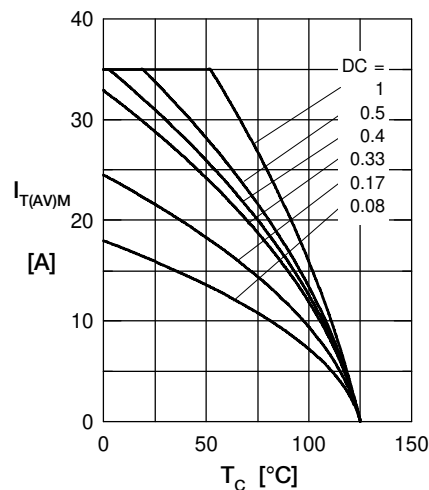


Fig. 5 Max. forward current vs. case temperature per thyristor

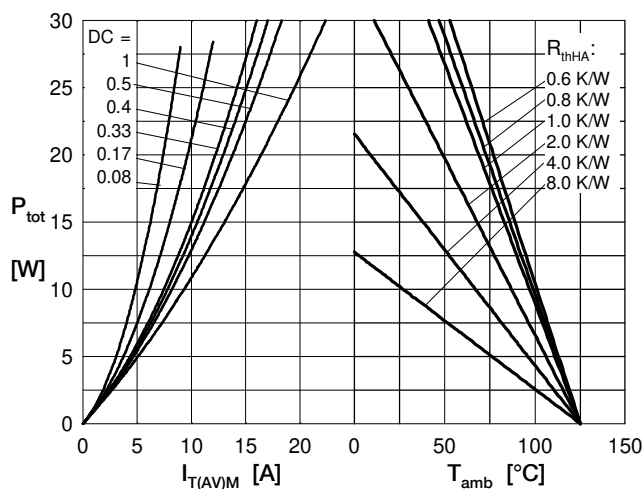


Fig. 4 Power dissipation vs. forward current and ambient temperature per thyristor

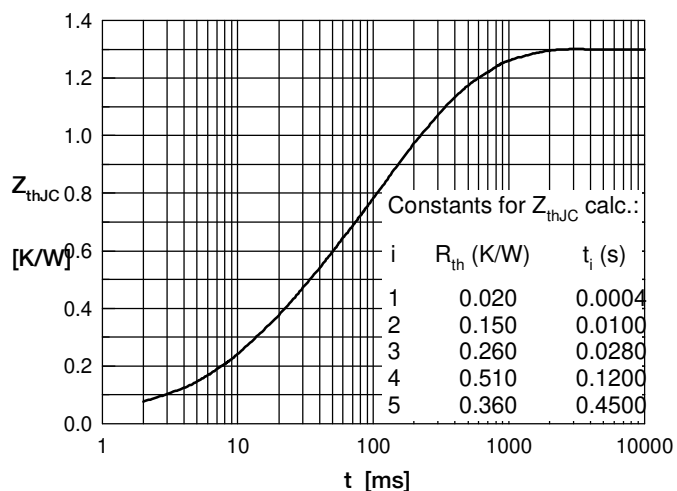


Fig. 6 Transient thermal impedance junction to case vs. time per thyristor